

G.R. No.

--

**DECEMBER 2021-ENDSEM EXAM**  
**S. Y. B. TECH. (E&TC) (SEMESTER - I)**  
**COURSE NAME: Engineering Circuit Analysis**  
**COURSE CODE: ETUA21202**  
**(PATTERN 2020)**

Time: [1Hr]

[Max. Marks: 30]

**Instructions to candidates:**

- 1) Answer Q.1 OR Q.2, Q.3 OR Q.4, Q.5 OR Q.6.
- 2) Figures to the right indicate full marks.
- 3) Use of scientific calculator is allowed
- 4) Use suitable data where ever required

Q.1 a Justify the following statements: [4]

- a) JFET is a voltage controlled device.
- b) The input resistance of JFET is higher than BJT.

Q.1 b The self-bias circuit using n-channel JFET has  $V_{DD}=18V$ ,  $R_D=4.7K\Omega$ ,  $R_S=1.5K\Omega$  and  $R_G=1M\Omega$ . [6]  
Determine the co-ordinates of Q point such as  $I_{DQ}$ ,  $V_{GSQ}$  and  $V_{DSQ}$ . Assume JFET has  $V_P=-4V$ ,  $I_{DSS}=8mA$  and  $g_m=5mS$ .

**OR**

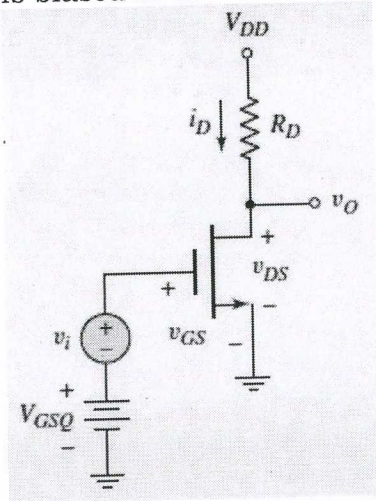
Q2 a For N channel JEFT, following data is given. [4]  
 $I_{DSS}=12mA$ ,  $V_P=-6V$ . Determine the value of trans-conductance ( $g_m$ ) and drain current  $I_D$  for  $V_{GS}=-2V$ .

Q2 b For self-biased N channel JFET CS amplifier with [6]  
bypass capacitor has following parameters:  $V_{DD}=20V$ ,  
 $R_G=1M\Omega$ ,  $R_S=500\Omega$ ,  $R_D=3.3K\Omega$ ,  $I_{DSS}=16mA$ ,  
 $V_P=-8V$ ,  $V_{GS}=-4V$  and  $r_d=50K\Omega$ .  
Determine  $A_v$ ,  $R_i$  and  $R_o$ .

Q.3 a Justify following statement [4]  
1. MOSFET has finite output resistance  
2. Current flows through the MOSFET below  $V_{TH}$ .

Q.3 b Determine the small-signal voltage gain ( $A_v$ ), [6]  
transconductance ( $g_m$ ) and output resistance ( $r_o$ ) of a  
MOSFET circuit. For the circuit in figure, assume following  
parameters:  $V_{GSQ}=2.12V$ ,  $V_{DD}=5V$  and  $R_D=2.5k\Omega$ ,  $V_{tn}=1$

V.  $K_n = 0.80 \text{ mA/V}^2$ , and  $\lambda = 0.02 \text{ V}^{-1}$ . Assume the transistor is biased in the saturation region.



**OR**

Q.4 a Calculate the transconductance of an n-channel MOSFET. Consider an n-channel MOSFET with parameters  $V_{tn} = 0.4 \text{ V}$ ,  $k'_n = 100 \mu\text{A/V}^2$ , and  $W/L = 25$ . Assume the drain current is  $I_D = 0.40 \text{ mA}$ . [4]

Q.4 b Derive the expression of voltage gain, input impedance and output impedance for N channel E-MOSFET CS amplifier with bypass capacitor. [6]

Q.5 a Calculate the voltage gain ( $A_f$ ), input impedance ( $Z_{if}$ ) and output impedance ( $Z_{of}$ ) for voltage-series feedback amplifier having  $A = -100$ ,  $R_i = 10 \text{ k}\Omega$ , and  $R_o = 20 \text{ k}\Omega$ , feedback factor ( $\beta$ ) = - 0.1. [4]

Q.5 b Illustrate with the neat circuit diagram Hartely oscillator and calculate oscillating frequency for  $L_1 = L_2 = 100 \mu\text{H}$  and  $C = 0.05 \mu\text{F}$ . [6]

**OR**

Q.6 a Sketch the block diagrams of current series and current shunt negative feedback topologies. [4]

Q.6 b Illustrate with the neat circuit diagram Colpitt Oscillator and calculate frequency of oscillations with  $C_1 = 24 \text{ nF}$ ,  $C_2 = 240 \text{ nF}$  and  $L = 10 \text{ mH}$ . [6]